

Please amend paragraph [0006] of the published application as follows:

[0006] The aforementioned and other features are accomplished, according to the present invention, by providing the main memory with error checking and correction apparatus and with apparatus identifying a signal group error, detected by the error checking and correction apparatus, as a the result of a failing bit position in the main memory or the error checking and correction memory. A failing bit position occurs in a non-volatile main memory implemented, for example, in flash technology when charge leakage changes the state of original or default state of the bit location. When a correctable data signal group error is identified in a read operation, the error is corrected and the data signal group is forwarded to the central processing unit. In addition, the address and the location of the location of the error are stored. An interrupt flag is available to the central processing unit. When the central processing unit can be interrupted, the central processing unit restores the location in the main memory where the error originated based on the stored address and location. The error correcting apparatus will thereafter not be burdened with correcting errors in the same bit location. Additionally, it is sometimes desirable to leave unprogrammed locations in the memory where tables can be updated without erasing the location contents. When the existing table is to be updated, the old information is programmed to be all logic "0"s. The corresponding correction bits are programmed to be all logic "0"s. The new table with its new correction bits is then programmed into new, usually successive locations that were previously all logic "1"s (all erased bits). To facilitate this requirement, additional circuitry is added to suppress optionally error corrections when the data and the correction bits are all in the logic "1"s or logic "0"s state.

Please amend paragraph [0013] of the published application as follows

[0013] Referring next to FIG. 2, a block diagram of data processing system 20 according to the present invention is illustrated. The central processing unit 11, the main memory unit 121, the error checking and correction memory 122, and the syndrome

calculation unit 124 perform essentially the same functions as described in FIG. 1. The bit correction unit 225 has an additional function as compared to the bit correction unit 125 of FIG. 1. In particular, when the bit location that is failing displays a logic "1" as compared to a correct logic "0", an interrupt request flag indicative of a failing zero bit position is generated. The present invention has three control signals that are illustrated by the erase condition valid flag 221, the correctable error interrupt enable 223, and the interrupt on zero fail only 224. These control signals are applied to the interrupt flag request unit 226. Based on these signals, the correction pattern latch unit 227 and the address latch 228 will store appropriate signal groups until the central processing unit 11 responds to a signal from the interrupt request flag unit 226. When the signal from the interrupt request flag unit 226 is serviced, the contents of the correction pattern latch 227 and the address latch 228 are forwarded to the central processing unit 11.

Please amend paragraph [0014] of the published application as follows:

[0014] The erase condition valid flag signal 221 provides that when a group memory of locations have had no data stored therein, the storage locations are in the erase condition and are indicative of logic "1"s, then no correction is done. Normally, the erased condition would generate a non-correctable error. Setting the erase condition valid flag allows this error to be ignored.

Please amend paragraph [0017] of the published application as follows:

[0017] Referring to FIG. 3, a process for responding to a detected error according to the present invention is shown. In step 31, the central processing unit is executing instructions of a program. In step 32, a read operation for retrieval of signal groups from the memory unit is instituted. A determination is made by the error checking and correction apparatus whether the retrieved signal group has an error[.] in step 33. When no error is detected in step 34, the procedure returns to step 31. When an error is detected [.] in step 33, then a determination is made whether the detected error (or errors) is correctable. When the detected error is not correctable in step 34, then the operation of the processing unit or at least that program is aborted. When in step 34 the

detected error is correctable, then the syndrome bits are calculated in step 35. In step 36, a determination is made whether the error is consistent with a failing bit in the main memory. When the detected failing bit is not consistent with a failing bit location in the main memory, then the erroneous bit is corrected in step 37 and the process returned to step 31 for execution of the program. When, in step 36, the detected error is consistent with a failing bit location, then the address of the signal group in which the error was detected and the correction pattern are stored in step 38. In step 39, an interrupt flag is set. The procedure then corrects the error and returns to step 31. In step 40, the interrupt flag is serviced by the central processing unit. The charge on the failing bit location is restored and the process returns to step 31.

Please amend paragraph [0019] of the published application as follows:

[0019] The operation of the present invention can be understood as follows. The invention relies on the fact that certain non-volatile memories, such as flash memory units or EEPROM (electrically erasable programmable read only memory) units, have a first state, i.e., a logic "0" state determined by a stored charge. When the stored charge decays a sufficient amount, then the bit location will be read as logic "1". The error checking and correction apparatus will determine the presence of an error state. In the example given above, the data signal groups stored in main memory is 64 bits. The check bit signal groups stored in the error checking and correction memory unit are 8 bits in length[[s]]. The syndrome bits would therefore be 72 bits in length. Such an error checking and correction technique can identify a single correctable error or can identify two errors that cannot be corrected. As will be clear to those skilled in the art, more elaborate error checking and correction schemes are available and can be used advantageously with the present invention. When the error checking and correction unit determines that a bit signal that should be a logic "0" is a logic "1", this error can be caused by a decay of the charge at the memory location. The response of the present invention, upon detection of an error that could be the result of decay of charge from a bit location, is to restore the charge at the bit location. The restoration of charge is the result of setting an interrupt flag. In addition, the address and the correction pattern ~~are~~

stored of the signal group having the error are stored. When the central processing unit responds to the interrupt flag, the address and correction pattern are transferred to the central processing unit. The central processing unit can restore the charge of the failing bit location or can restore either the signal group locations in the main memory or in the error checking and correcting memory unit depending on the position of the correctable error.